

## Features

- ◆ Schottky Barrier Chip
- ◆ High Thermal Reliability
- ◆ Patented Super Barrier Rectifier Technology
- ◆ High Forward Surge Capability
- ◆ Ultra Low Power Loss, High Efficiency Excellent
- ◆ High Temperature Stability Plastic
- ◆ Material-UL flammability 94V-0

## Mechanical Data

**Case :** JEDEC TO-277 Molded plastic body

**Terminals :** Solder plated, solderable per MIL-STD-750, Method 2026

**Polarity :** Polarity symbol marking on body

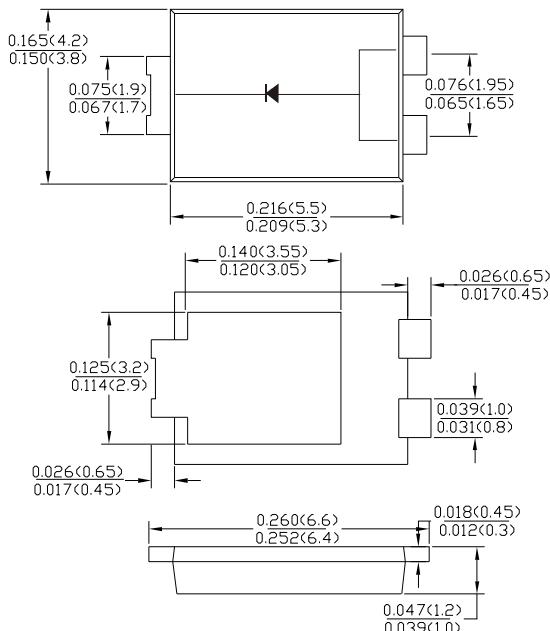
**Mounting Position :** Any

**Weight :** 0.003 ounce, 0.0092 grams

**TO-277B**

RoHS  
COMPLIANT

Pb-Free



Dimensions in inches and (millimeters)

## Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter	SYMBOLS	SS(B) 1045L	SS(B) 1050L	SS(B) 1060L	SS(B) 1080L	SS(B) 10100L	SS(B) 10150L	UNITS
Marking Code		SB 1045L	SB 1050L	SB 1060L	SB 1080L	SB 10100L	SB 10150L	
Maximum repetitive peak reverse voltage	V <sub>RMM</sub>	45	50	60	80	100	150	V
Maximum RMS voltage	V <sub>RMS</sub>	32	35	42	56	70	105	V
Maximum DC blocking voltage	V <sub>DC</sub>	45	50	60	80	100	150	V
Maximum average forward rectified current 0.375" (9.5mm) lead length (see fig.1) (Note1)	I <sub>(AV)</sub>	10.0						A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) (Note2)	I <sub>FSM</sub>	275.0						A
Maximum instantaneous forward voltage at 10.0A	V <sub>F</sub>	0.42	0.45	0.47	0.75	0.78		V
Maximum DC reverse current TA=25°C at rated DC blocking voltage TA=100°C	I <sub>R</sub>	0.3						mA
Typical junction capacitance (NOTE 1)	C <sub>J</sub>	80						pF
Typical thermal resistance (NOTE 2)	R <sub>θJA</sub>	15.0						°C/W
Operating junction and storage	T <sub>J</sub>	-65 to +150						°C
Storage temperature range	T <sub>STG</sub>	-65 to +150						°C

Note: 1. Valid Provided that are kept at ambient temperature at a distance of 9.5mm from the case.

2. Fr-4pcb.2oz.Copper, minimum recommend pad layout .18.8mm×14.4mm. Anode pad dimensions 5.6mm×14.4mm.

## Ratings And Characteristic Curves

Fig.1 - Forward Current Derating Curve

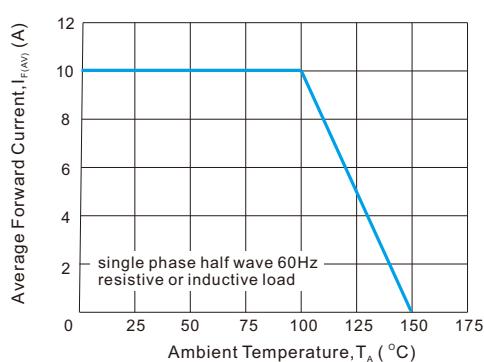


Fig.3: Surge Forward Current Capability

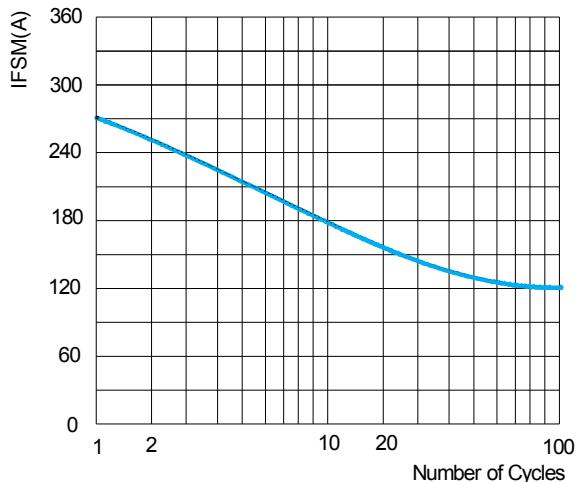


Fig.2 :Instantaneous Forward Voltage

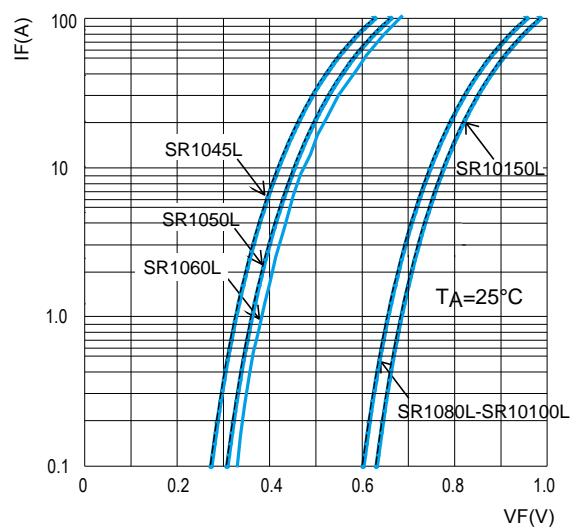
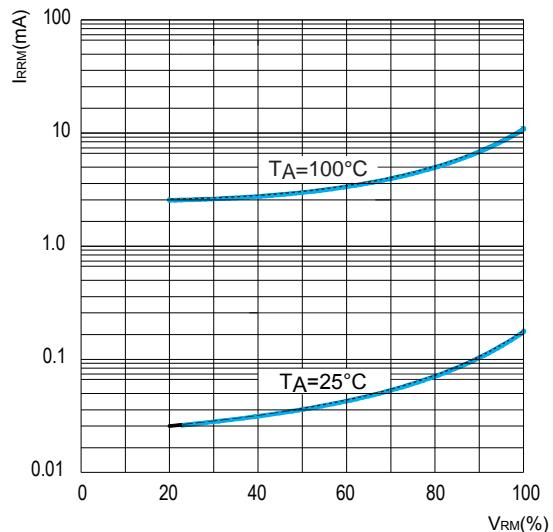


Fig.4: Typical Reverse Characteristics



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